

High speed CMOS logic IC ELM7SHT04xB TTL input inverter

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■General description

ELM7SHT04xB is CMOS inverter with TTL input which is suitable for battery-operated devices because of its low voltage and ultra high speed operation. The low power consumption contributes to longer battery life, which allows long time operation of devices. The internal circuit which provides high noise immunity and stable output is composed of 3 stages, including buffered output.

■Features

- TTL level input : Vil = 0.8V(Max.), Vih = 2.0V(Min.)
- Same electrical characteristic and high speed operation as 74VHC series
- Low consumption current : Idd=1.0 μ A(Max.)(Top=25°C)
- Wide power voltage range : 2.0V to 5.5V
- Wide input voltage range : Vih=5.5V(Max.)(Vdd=0 to 5.5V)
- High speed : Tpd=2ns(Typ.)(Vdd=5.0V)
- Small package : SOT-25, SC-70-5(SOT-353)
- Same function and pin configuration as ELM7SxxB

■Application

- Cell phones
- Digital cameras
- Portable electrical appliances like PDA, etc.
- Computers and peripherals
- Digital electrical appliances like LCD TV sets, DVD recorders/players, STB, etc.
- Modification inside print board, adjustment of timing, solution to noise
- Power voltage change from 5V to 3V

■Selection guide

ELM7SHT04xBEL

Symbol	Function	
a	Function	T04: TTL input Inverter
b	Package	M: SOT-25 T : SC-70-5(SOT-353)
c	Product version	B
d	Taping direction	EL: Refer to PKG file

ELM7SH T04 x B EL
↑ ↑ ↑ ↑
a b c d

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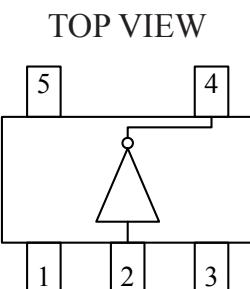
■Maximum absolute ratings

Parameter	Symbol	Limit	Unit
Power supply voltage	Vdd	-0.5 to +6.0	V
Input voltage	Vin	-0.5 to +6.0	V
Output voltage	Vout	-0.5 to Vdd+0.5	V
Input protection diode current	Iik	-20	mA
Output parasitic diode current	Iok	± 20	mA
Output current	Iout	± 25	mA
VDD/GND current	Idd, Ignd	± 50	mA
Power dissipation	Pd	150	mW
Storage temperature	Tstg	-65 to +150	°C

■Suggested operating condition

Parameter	Symbol	Limit	Unit
Power voltage	Vdd	2.0 to 5.5	V
Input voltage	Vin	0 to 5.5	V
Output voltage	Vout	0 to Vdd	V
Operating temperature	Top	-40 to +85	°C
High-input down-time	tr, tf	Vdd=3.3±0.3V Vdd=5.0±0.5V	0 to 200 0 to 100
			ns

■Pin configuration



Pin No.	Pin name
1	NC
2	INY
3	GND
4	OUTX
5	VDD

Input	Output
INY	OUTX
Low	High
High	Low

■DC electrical characteristics

Parameter	Sym.	Vdd	Top=25°C			Top=-40 to +85°C		Unit	Condition
			Min.	Typ.	Max.	Min.	Max.		
High level input voltage	Vih	4.5 to 5.5	2.0	-	-	2.0	-	V	-
Low level input voltage	Vil	4.5 to 5.5	-	-	0.8	-	0.8		-
High level output voltage	Voh	4.5	4.4	4.5	-	4.4	-	V	Vin=Vil Ioh=-50μA Ioh=-8mA
		4.5	3.94	-	-	3.8	-		
Low level output voltage	Vol	4.5	-	0.0	0.1	-	0.1	V	Vin=Vih Iol=50μA Ioh=8mA
		4.5	-	-	0.36	-	0.44		
Input current	Iin	5.5	-0.1	-	0.1	-1.0	1.0	μA	Vin=Vdd or GND
Static current	Idd	5.5	-	-	1.0	-	10.0	μA	Vin=Vdd or GND
	Iddt	5.5	-	-	1.35	-	1.5	mA	Vin=3.4V

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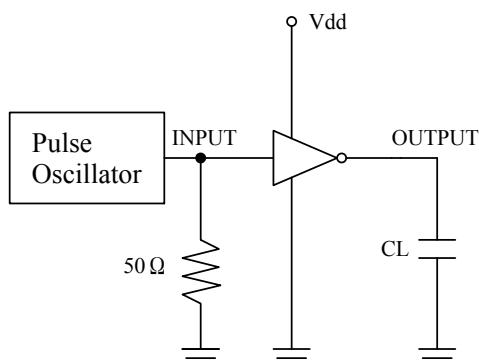
■AC electrical characteristics

tr=tf=3ns

Parameter	Sym.	Vdd	CL	Top=25°C			Top=-40 to +85°C		Unit	Condition
				Min.	Typ.	Max.	Min.	Max.		
Propagation delay-time	tPLH	5.0±0.5	15	-	3.0	7.0	1.0	8.0	ns	Refer to test circuit
	tPHL		50	-	4.0	10.5	1.0	12.0		
Input capacity	Cin	5.0	-	-	2.0	10.0	-	10.0	pF	Vin=Vdd or GND
Equivalent inner capacity	Cpd	-	-	-	8.9	-	-	-	pF	f=1MHz

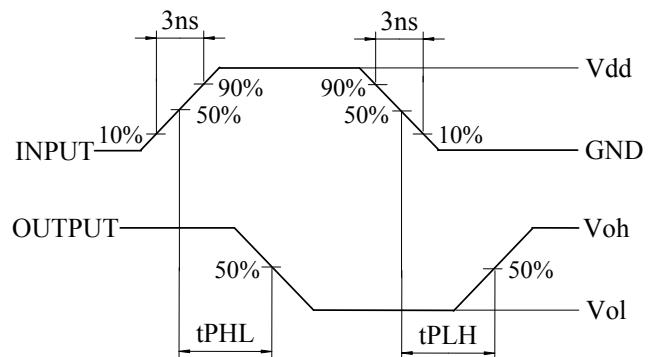
* Cpd is IC's inner equivalent capacity which is calculated from non-loaded operating current consumption referred to test circuit. Averaged operating current consumption at non load is calculated as following formula: $I_{dd(\text{opr})} = C_{pd} \cdot V_{dd} \cdot f_{in} + I_{dd}$

■Test circuit



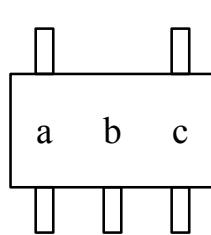
* Output should be opened when measuring current consumption.

■Measured wave pattern

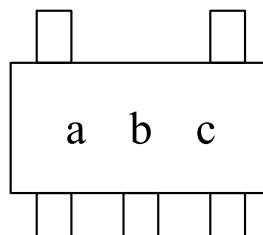


■Marking

SC-70-5



SOT-25



Sym.	Mark	Content
a	F	ELM7SH series
b	7	ELM7SHT04xB
c	A to Z (except I, O, X)	Lot No.